Linear IC General purpose Converter cmos

D/A Converter for Digital Tuning

(8 channels. 8-bit, with OP amplifier)

MB88347

■ DESCRIPTION

The MB88347 features 8 channels of 8-bit D/A converters (with output amplifiers). The output amplifier provides high current drive capability. As data is input via a serial link, only three control lines are required, and cascaded connections can be used.

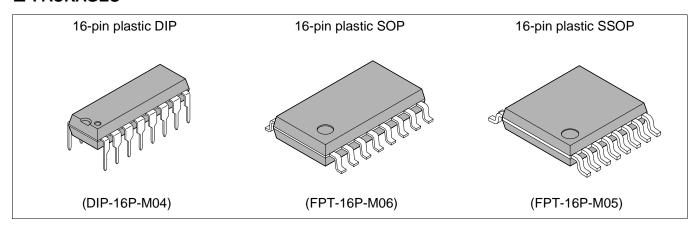
The MB88347 is suitable for electronic volumes and replacement for potentiometers for adjustment, in addition to normal D/A converter applications.

■ FEATURES

- Low power consumption (2 mW/ch)
- · Small package
- Integrating 8 channels of R-2R type 8-bit D/A converter.

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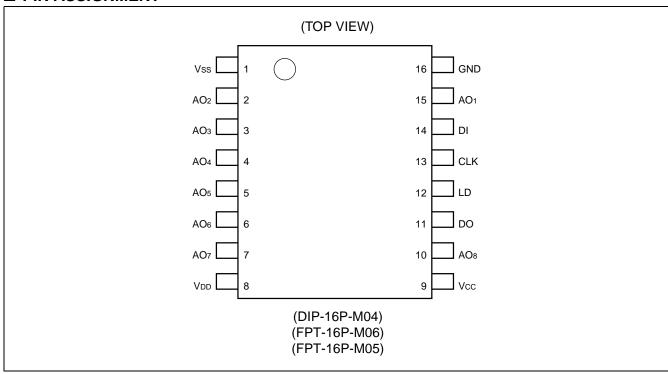
■ PACKAGES





- Built-in analog output amplifier (Max +1.0 mA sink/source current)
- Analog output range : 0 to Vcc
- The range of D/A conversion can be independently set by separated the power supply for MCU interface and OP amplifier and the power supply for D/A converter.
- Capable of being controlled directly by a 3-V MCU (input voltage: "H" = 0.5 V cc, "L" = 0.2 V cc)
- Serial data input, 2.5 MHz operation
- CMOS process
- Package lineup : DIP 16-pin, SOP 16-pin, SSOP 16-pin

■ PIN ASSIGNMENT

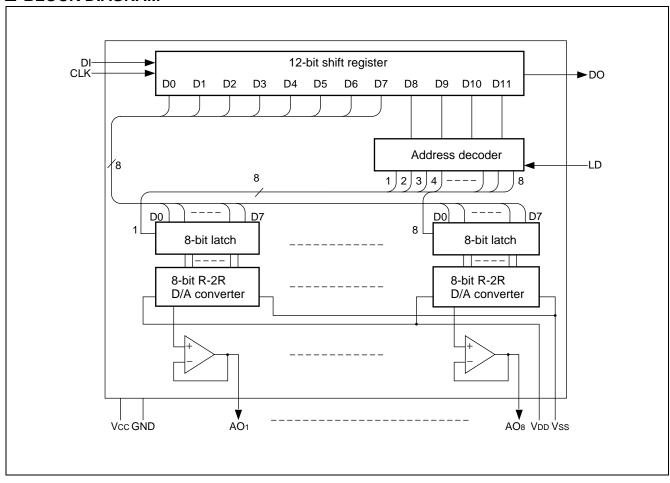


■ PIN DESCRIPTION

Pin No.	Symbol	I/O	Pin name	Function			
14	DI*	I	Data input pin	Serial data input pin. This pin inputs 12-bit length serial data.			
11	DO	0	Data output pin	This pin outputs MSB bit data of 12-bit shift register.			
13	CLK*	I	Shift clock input pin	Shift clock input pin. The input signal from the DI pin is inputted to a 12-bit shift register on the rising edge of the shift clock.			
12	LD*	I	Load signal input pin	If input "H" level to LD pin, the data of shift register is loaded to the decoder and the register for D/A output			
15	AO ₁						
2	AO ₂						
3	АО₃						
4	AO ₄	0	D/A output pin	These pins are 8-bit D/A output with OP amplifier.			
5	AO ₅		Dirit output pili	Those pine are e sit sin to diput with or ampliner.			
6	AO ₆						
7	AO ₇						
10	AO ₈						
9	Vcc	_	Power supply pin	Power supply pin of MCU interface and OP amplifier			
16	GND		Ground pin	Ground pin of MCU interface and OP amplifier			
8	V _{DD}		Power supply pin	Power supply pin of D/A converter			
1	Vss		Ground pin	Ground pin of D/A converter			

^{*:} DI, CLK, and LD pins are fixed to "L" level at non transfer.

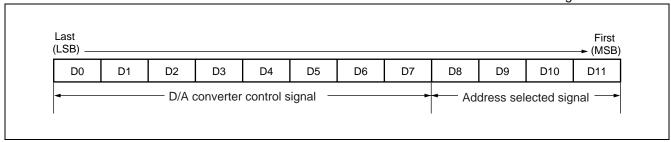
■ BLOCK DIAGRAM



■ DATA FOR CHIP CONTROL

1. Data for Shift Register

- MB88347 has 12-bit shift register for chip control.
- It is necessary to set the data as following configuration to 12-bit shift register.
- The data consists of 12 bits: a 4-bit address selection and an 8-bit D/A converter control signal.



2. D/A Converter Control Signal

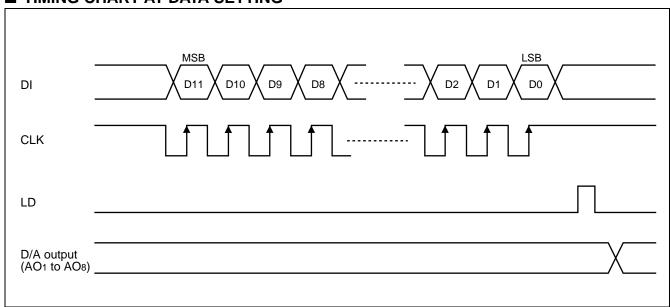
			D/A converter output voltage					
D0	D1	D2	D3	D4	D5	D6	D7	DIA converter output voltage
0	0	0	0	0	0	0	0	≑ Vss
1	0	0	0	0	0	0	0	
0	1	0	0	0	0	0	0	
5	\$	5	5	\$	\$	5	\$	Ş
0	1	1	1	1	1	1	1	
1	1	1	1	1	1	1	1	≑ V _{DD}

 $V_{LB} = (V_{DD} - V_{SS})/255$

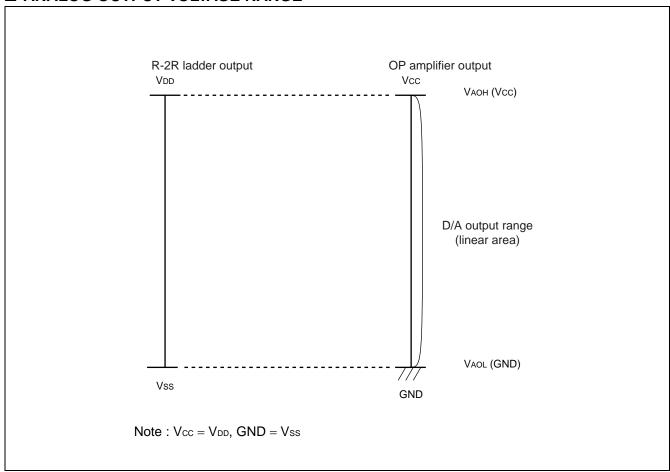
3. Address Selected Signal

	Input da	ta signal		Address selected
D8	D9	D10	D11	Address selected
0	0	0	0	Don't Care
0	0	0	1	AO ₁ selected
0	0	1	0	AO ₂ selected
0	0	1	1	AO ₃ selected
0	1	0	0	AO ₄ selected
0	1	0	1	AO₅ selected
0	1	1	0	AO ₆ selected
0	1	1	1	AO ₇ selected
1	0	0	0	AO ₈ selected
1	0	0	1	Don't Care
1	0	1	0	Don't Care
1	0	1	1	Don't Care
1	1	0	0	Don't Care
1	1	0	1	Don't Care
1	1	1	0	Don't Care
1	1	1	1	Don't Care

■ TIMING CHART AT DATA SETTING



■ ANALOG OUTPUT VOLTAGE RANGE



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Rat	Unit	
raiailletei	Symbol	Condition	Min	Max	Onit
Power supply voltage	Vcc		- 0.3	+ 7.0	V
Fower supply voltage	V _{DD}	The case that GND is reffered.	- 0.3*	+ 7.0*	V
Input voltage	Vin	Ta = +25 °C	- 0.3	Vcc + 0.3	V
Output voltage	Vouт		- 0.3	Vcc + 0.3	V
Power consumption	PD	_		250	mW
Operating temperature	Та	_	- 40	+ 85	°C
Storage temperature	orage temperature Tstg		- 55	+ 150	°C

^{*:} $V_{CC} \ge V_{DD}$

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Condition	Va	Unit		
Parameter	Symbol	Condition	Min	Max	Oilit	
Power supply Voltage 1	Vcc	_	4.5	5.5	V	
Fower supply voltage 1	GND	_		0	V	
Power supply Voltage 2	V _{DD}	V _{DD} – V _{SS} ≥ 2.0 V	2.0	Vcc	V	
Power supply voltage 2	Vss	VDD - VSS ≥ 2.0 V	GND	Vcc - 2.0	V	
Analog output source current	Ial	_		1.0	mA	
Analog output sink current	I AH	_		1.0	mA	
Oscillation limited output capacitance	CoL	_		1.0	μF	
Digital data setting range	_	_	#00	#FF	—	
Operating temperature	Та	_	- 40	+ 85	°C	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

> Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

> No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics

(1) Digital block

(VDD, VCC = + 5 V \pm 10% (VCC \geq VDD) , GND, Vss = 0 V, Ta = - 40 °C to + 85 °C)

Doromotor	Symbol	Din nome	Conditions		l lmi4		
Parameter	Symbol	Pin name	Conditions	Min	Тур	Max	Unit
Power supply voltage	Vcc		_	4.5	5.0	5.5	V
Power supply current	Icc	Vcc	At CLK = 1 MHz operating (at no load) At Ta = -20 °C to $+85$ °C	_	0.8	1.8	mA
			At CLK = 1 MHz operating (at no load) At Ta = -40 °C to $+85$ °C		0.8	2.1	
Input leakage current	lilk	CLK	V _{IN} = 0 to V _{CC}	-10		10	μΑ
"L" level input voltage	VIL	DI	_		_	0.2 Vcc	V
"H" level input voltage	Vıн	LD	_	0.5 Vcc	_		V
"L" level output voltage	Vol	DO	loL = 2.5 mA	_		0.4	V
"H" level output voltage	Vон		Іон = -400 μΑ	Vcc - 0.4	_	_	V

Note : Io_L and Io_H are output load current.

(2) Analog block

(VDD, VCC = + 5 V \pm 10% (VCC \geq VDD) , GND, Vss = 0 V, Ta = - 40 °C to + 85 °C)

Parameter		Pin name	Conditions		Value			
•		Pin name	Conditions	Min	Тур	Max	Unit	
Consumption current	I _{DD}	V _{DD}	No load	_	1.0	1.5	mA	
Analog power	V _{DD}	V _{DD}	V _{DD} – Vss ≥ 2.0 V	2.0		Vcc	V	
supply voltage	Vss	Vss	VDD - VSS ≥ 2.0 V	GND		Vcc - 2.0	V	
Resolution	Res		_	_	8	_	bit	
Monotonic increase	Rem	AO₁ to		_	8	_	bit	
Non linearity error*1	LE	AO1 to	No load V _{DD} ≤ V _{CC} − 0.1 V	-1.5		1.5	LSB	
Differential linearity error*2	DLE		V _{SS} ≥ 0.1 V	-1.0		1.0	LSB	
Output minimum voltage 1	V _A OL1		$\begin{aligned} V_{DD} &= V_{CC} \\ V_{SS} &= GND = 0.0 \ V \\ I_{AL} &= 0 \ \mu A \\ Digital \ data &= \#00 \end{aligned}$	Vss	_	Vss + 0.1	V	
Output minimum voltage 2	V _{AOL2}		$\begin{aligned} V_{DD} &= V_{CC} = 5.0 \text{ V} \\ V_{SS} &= GND = 0.0 \text{ V} \\ I_{AL} &= 500 \mu\text{A} \\ \text{Digital data} &= \#00 \end{aligned}$	Vss - 0.2	Vss	Vss + 0.2	V	
Output minimum voltage 3	V _A OL3	AO ₁ to AO ₈	V _{DD} = V _{CC} = 5.0 V V _{SS} = GND = 0.0 V I _{AH} = 500 μA Digital data = #00	Vss	_	Vss + 0.2	V	
Output minimum voltage 4	V _{AOL4}		V _{DD} = V _{CC} = 5.0 V V _{SS} = GND = 0.0 V I _{AL} = 1.0 mA Digital data = #00	Vss - 0.3	Vss	Vss + 0.3	V	
Output minimum voltage 5	V _{AOL5}		V _{DD} = V _{CC} = 5.0 V V _{SS} = GND = 0.0 V I _{AH} = 1.0 mA Digital data = #00	Vss	_	Vss + 0.3	V	

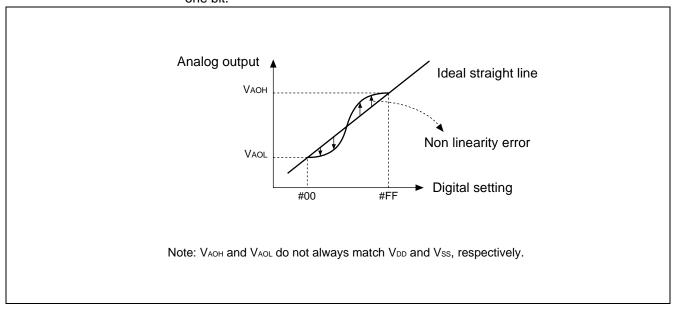
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(Vdd, Vcc = + 5 V \pm 10% (Vcc \geq Vdd) , GND, Vss = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Symbol Pin name		Conditions		Unit		
Farameter	Symbol	Filitiallie	Conditions	Min	Тур	Max	Oiii
Output maximum voltage 1	Vaoh1		$\begin{aligned} &V_{DD} = V_{CC} \\ &V_{SS} = GND = 0.0 \ V \\ &I_{AL} = 0 \ \mu A \\ &Digital \ data = \#FF \end{aligned}$	V _{DD} - 0.1	_	V _{DD}	>
Output maximum voltage 2	V _{AOH2}		$V_{DD} = V_{CC} = 5.0 \text{ V}$ $V_{SS} = GND = 0.0 \text{ V}$ $I_{AL} = 500 \mu\text{A}$ $Digital \text{ data} = \#FF$	V _{DD} - 0.2	_	V _{DD}	V
Output maximum voltage 3	Vаонз	AO ₁ to AO ₈	$\begin{split} V_{DD} &= V_{CC} = 5.0 \text{ V} \\ V_{SS} &= GND = 0.0 \text{ V} \\ I_{AH} &= 500 \mu\text{A} \\ \text{Digital data} &= \#FF \end{split}$	V _{DD} - 0.2	V _{DD}	V _{DD} + 0.2	>
Output maximum voltage 4	Vаон4		$V_{DD} = V_{CC} = 5.0 \text{ V}$ $V_{SS} = GND = 0.0 \text{ V}$ $I_{AL} = 1.0 \text{ mA}$ Digital data = #FF	V _{DD} - 0.3	_	V _{DD}	>
Output maximum voltage 5	Vаон5		$V_{DD} = V_{CC} = 5.0 \text{ V}$ $V_{SS} = GND = 0.0 \text{ V}$ $I_{AH} = 1.0 \text{ mA}$ Digital data = #FF	V _{DD} - 0.3	V _{DD}	V _{DD} + 0.3	V

^{*1 :} Non linearity error

*2 : Differential linearity error : The error from the ideal increment given when the digital value is incremented by one bit.



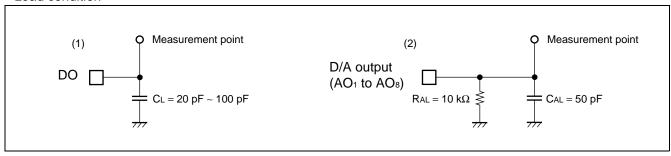
[:] The error of the I/O curve from the ideal straight line between output voltages at "00" and "FF".

2. AC Characteristics

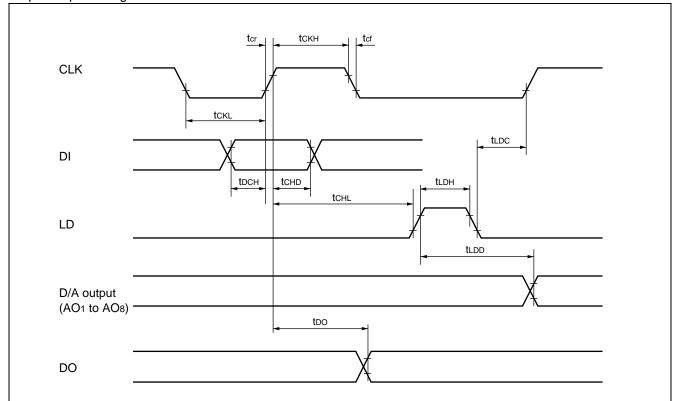
(Vdd, Vcc = + 5 V \pm 10% (Vcc \geq Vdd) , GND, Vss = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Symbol	Conditions	Va	Unit	
Faranietei	Syllibol	Conditions	Min	Max	Onit
"L" level clock pulse width	t ckl	_	200	_	ns
"H" level clock pulse width	t ckH	_	200	_	ns
Clock rising time Clock falling time	tcr tcr	_		200	ns
Data setup time	t DCH	_	30	_	ns
Data hold time	t chd	_	60	_	ns
Load setup time	t chL	_	200	_	ns
Load hold time	t LDC	_	100	_	ns
"H" level load pulse width	t LDH	_	100	_	ns
Data output delay time	t DO	Refer to "Load condition (1)".	70	350	ns
D/A output settling time	t LDD	Refer to "Load condition (2)".		100	μS

• Load condition

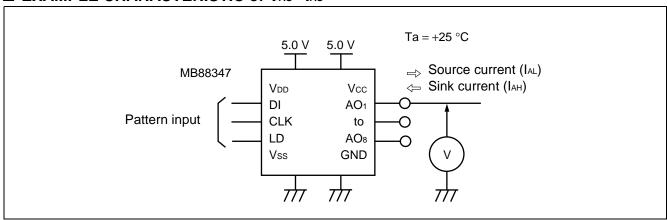


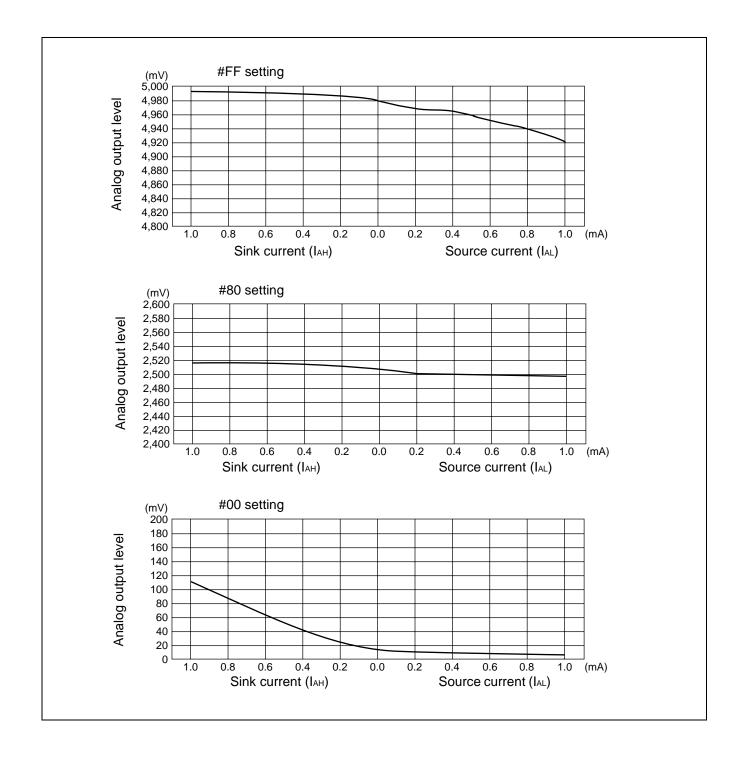
• Input/output timing



Note : The D/A output evaluation level is 90% and 10% of Vcc. The other evaluation level is 80% and 20% of Vcc.

■ EXAMPLE CHARACTERISTIC of Vao - Iao

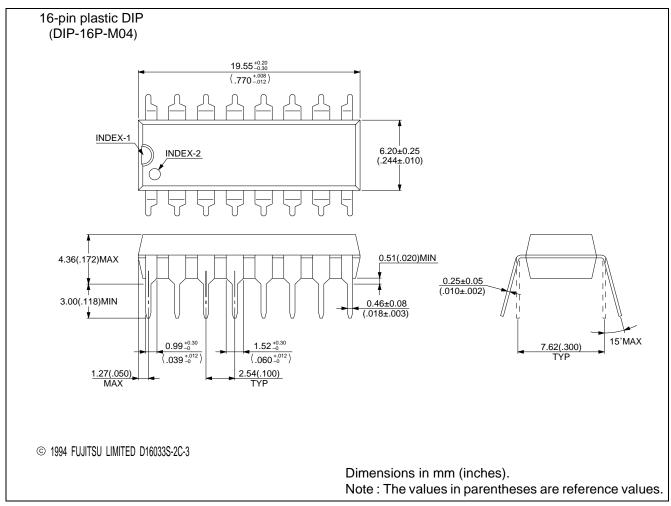


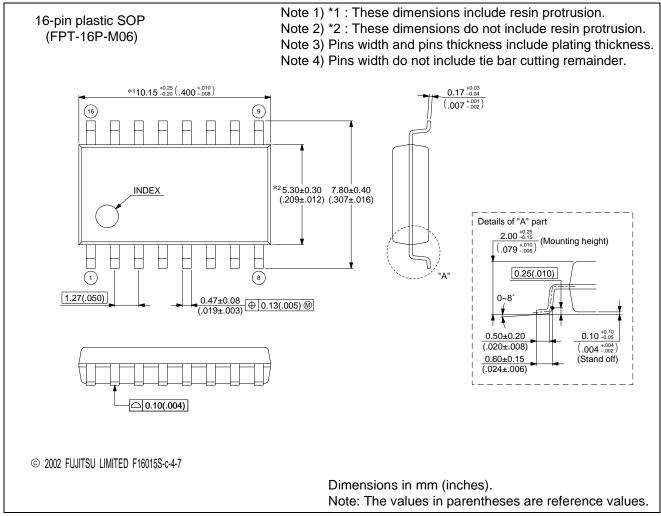


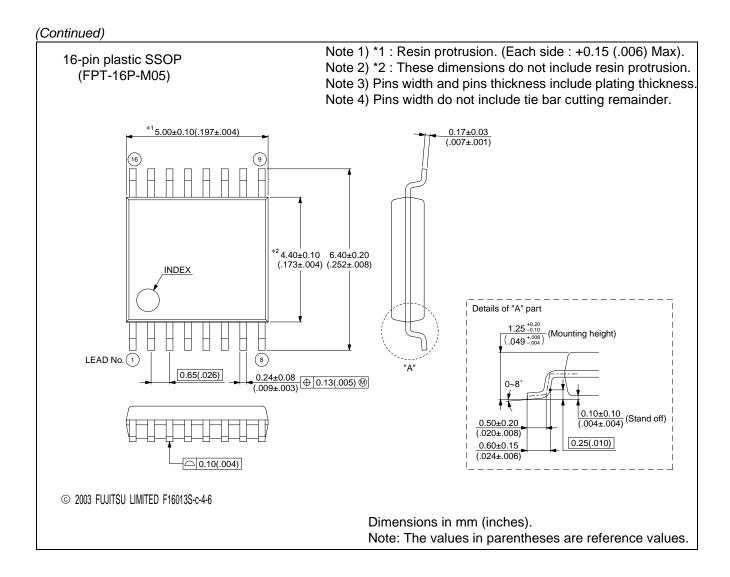
■ ORDERING INFORMATION

Part No.	Package	Remarks
MB88347P	16-pin plastic DIP (DIP-16P-M04)	
MB88347PF	16-pin plastic SOP (FPT-16P-M06)	
MB88347PFV	16-pin plastic SSOP (FPT-16P-M05)	

■ PACKAGE DIMENSIONS







FUJITSU MICROELECTRONICS LIMITED

Shinjuku Dai-Ichi Seimei Bldg. 7-1, Nishishinjuku 2-chome, Shinjuku-ku, Tokyo 163-0722, Japan Tel: +81-3-5322-3347 Fax: +81-3-5322-3387 http://jp.fujitsu.com/fml/en/

For further information please contact:

North and South America

FUJITSU MICROELECTRONICS AMERICA, INC. 1250 E. Arques Avenue, M/S 333
Sunnyvale, CA 94085-5401, U.S.A.
Tel: +1-408-737-5600 Fax: +1-408-737-5999
http://www.fma.fujitsu.com/

Europe

FUJITSU MICROELECTRONICS EUROPE GmbH Pittlerstrasse 47, 63225 Langen, Germany Tel: +49-6103-690-0 Fax: +49-6103-690-122

Korea

FUJITSU MICROELECTRONICS KOREA LTD. 206 KOSMO TOWER, 1002 Daechi-Dong, Kangnam-Gu,Seoul 135-280 Korea

http://emea.fujitsu.com/microelectronics/

Tel: +82-2-3484-7100 Fax: +82-2-3484-7111

http://www.fmk.fujitsu.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD.

151 Lorong Chuan, #05-08 New Tech Park,
Singapore 556741

Tel: +65-6281-0770 Fax: +65-6281-0220

http://www.fujitsu.com/sg/services/micro/semiconductor/

FUJITSU MICROELECTRONICS SHANGHAI CO., LTD. Rm.3102, Bund Center, No.222 Yan An Road(E), Shanghai 200002, China Tel: +86-21-6335-1560 Fax: +86-21-6335-1605 http://cn.fujitsu.com/fmc/

FUJITSU MICROELECTRONICS PACIFIC ASIA LTD.
10/F., World Commerce Centre, 11 Canton Road
Tsimshatsui, Kowloon
Hong Kong
Tel: +852-2377-0226 Fax: +852-2376-3269
http://cn.fujitsu.com/fmc/tw

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